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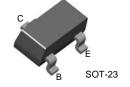


October 2008

### PN100/PN100A/MMBT100/MMBT100A **NPN General Purpose Amplifier**

- · This device is designed for general purpose amplifier applications at collector currents to 300mA.
- Sourced from process 10.





1. Emitter 2. Base 3. Collector Mark: PN100/PN100A

### Absolute Maximum Ratings\* Ta = 25°C unless otherwise noted

Symbol	Parameter	Units			
V <sub>CEO</sub>	Collector-Emitter Voltage	45			
V <sub>CBO</sub>	Collector-Base Voltage				
V <sub>EBO</sub>	Emitter-Base Voltage				
I <sub>C</sub>	Collector current	500			
T <sub>J</sub> , T <sub>sta</sub>	Junction and Storage Temperature				

<sup>\*</sup> These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

- These ratings are based on a maximum junction temperature of 150 degrees C.
   These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

### Thermal Characteristics T<sub>A</sub>=25°C unless otherwise noted

		Max.				
Symbol	Parameter	PN100 *MMBT100 PN100A *MMBT100A		Units		
P <sub>D</sub>	Total Device Dissipation	625	350	mW		
	Derate above 25°C	5.0	2.8	mW/°C		
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3		°C/W		
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	357	°C/W		

Device mounted on FR-4 PCB 1.6" × 1.6" × 0.06."

<sup>\*</sup> Pulse Test: Pulse Width≤300μs, Duty Cycle≤2%

### Electrical Characteristics $\rm T_{C}{=}25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Condition	Test Condition			Units	
Off Charac	teristics						
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	$I_C = 10\mu A, I_E = 0$	$I_{C} = 10\mu A, I_{E} = 0$				
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage *	$I_{C} = 1 \text{mA}, I_{B} = 0$		45		V	
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	$I_E = 10\mu A, I_C = 0$		6.0		V	
I <sub>CBO</sub>	Collector-Base Cutoff Current	V <sub>CB</sub> = 60V			50	nA	
I <sub>CES</sub>	Collector-Emiitter Cutoff Current	V <sub>CE</sub> = 40V			50	nA	
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 4V			50	nA	
On Charact	teristics	•			•		
h <sub>FE</sub>	DC Current Gain	$I_C = 100\mu A, V_{CE} = 1.0V$ $I_C = 10mA, V_{CE} = 1.0V$	100 100A 100	80 240 100	450		
		I <sub>C</sub> = 100mA, V <sub>CE</sub> = 1.0V* I <sub>C</sub> = 150mA, V <sub>CE</sub> = 5.0V *	100A 100 100A	300 100 100 100	600 350		
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	$I_C = 10\text{mA}, I_B = 1.0\text{mA}$ $I_C = 200\text{mA}, I_B = 20\text{mA}$	•		0.2 0.4	V V	
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	$I_C = 10\text{mA}, I_B = 1.0\text{mA}$ $I_C = 200\text{mA}, I_B = 20\text{mA}$			0.85 1.0	V V	
Small Sign	al Characteristics	•			•		
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CE} = 20V, I_{C} = 20mA$		250		MHz	
C <sub>obo</sub>	Output Capacitance	V <sub>CB</sub> = 5.0V, f = 1.0MHz			4.5	pF	
NF	Noise Figure	$I_C = 100 \mu A$ , $V_{CE} = 5.0 V$ $R_G = 2.0 k \Omega$ , $f = 1.0 K H z$	100 100A		5.0 4.0	dB dB	

<sup>\*</sup> Pulse Test: Pulse Width  $\leq 300 \mu s$ , Duty Cycle  $\leq 2.0\%$ 

### **Typical Characteristics**

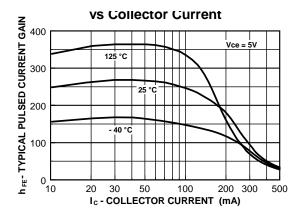


Figure 1. Typical Pulsed Current Gain vs Collector Current

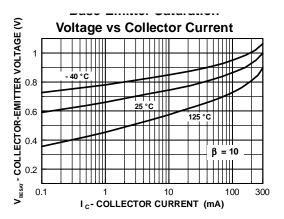


Figure 3. Base-Emitter Saturation Voltage vs Collector Current

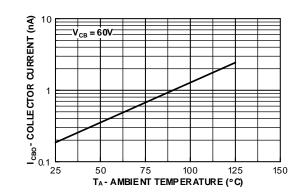


Figure 5. Collector Cutoff Current vs Ambient Temperature

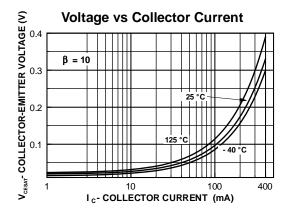


Figure 2. Collector-Emitter Saturation Voltage vs Collector Current

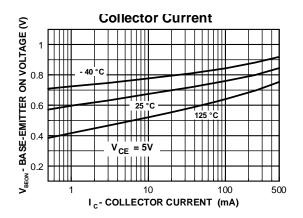


Figure 4. Base-Emitter On Voltage vs Collector Current

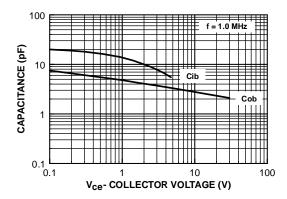


Figure 6. Input and Output Capacitance vs Reverse Voltag

### Typical Characteristics (Continued)

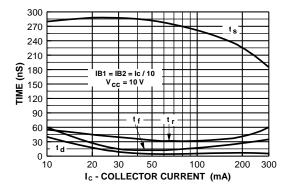


Figure 7. Switching Times vs Collector Current

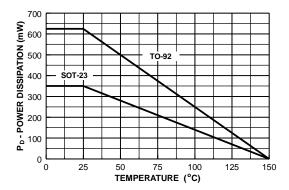
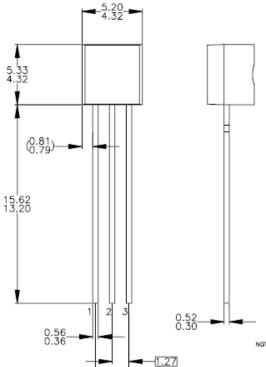
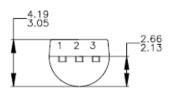


Figure 8. Power Dissipation vs Ambient Temperature

### **Package Dimension (TO92)**





2.54

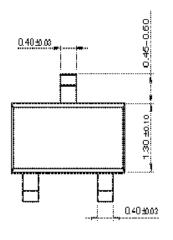
NOTES: UNLESS OTHERWISE SPECIFIED

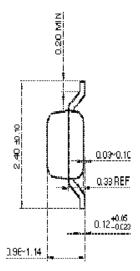
- DRAWING WITH REFERENCE TO JEDEC TO-92 RECOMMENDATIONS. ALL DIMENSIONS ARE IN MILLIMETERS. DRAWING CONFORMS TO ASME Y14.5M-1994. TO-92 (92,94,96,97,98) PIN CONFIGURATION:

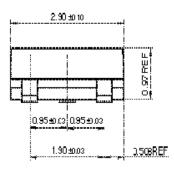
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ď	Р	F	М	Р	F	М	В	F	м	Р	F	М	Р	F	М	l
1	Ε	S	S	Ε	S	S	В	D	G	С	G	D	C	G	D	l
2	В	D	G	C	G	D	Ε	S	S	В	D	G	Ε	S	S	l
3	Ċ	G	D	В	D	0	c	0	D	Ε	S	S	В	D	G	l
LEGEND:   P - BIPOLAR   E - EMITTER   D - DRAIN   F - JFET   B - BASE   S - SOURCE   M - DMOS   C - COLLECTOR   G - GATE																

- E) FOR PACKAGE 92, 94, 96, 97 AND 98: PIN CONFIGURATION DRAIN "D" AND SOURCE "S" ARE INTERCHANGEAGLE AT JFET "F" OPTION. F) DRAWING FILENAME: MKT—ZAOJOREVS.

### Package Dimension (SOT23)











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